



MPC816X1 Series

DIP4, DC Input, Photo Transistor Coupler

Description

The MPC-816X1 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic DIP4 package with different lead forming options. With the robust coplanar double mold structure, MPC-816X1 series provide the most stable isolation feature.

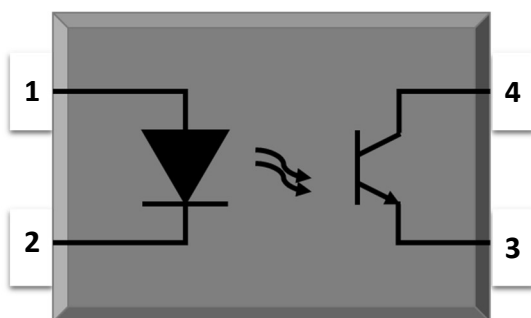
Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- Operating temperature range - 55 °C to 110 °C
- RoHS & REACH Compliance
- MSL class 1
- Halogen free (Optional)
- Regulatory Approvals
 - UL - UL1577
 - VDE - EN60747-5-5(VDE0884-5)
 - CQC – GB4943.1, GB8898

Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

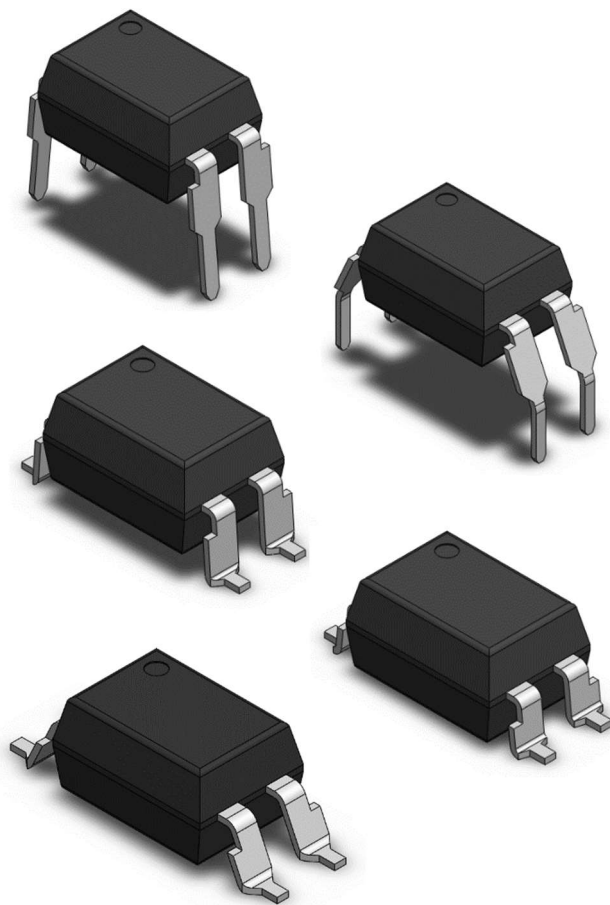
SCHEMATIC



PIN DEFINITION

1. Anode
2. Cathode
3. Emitter
4. Collector

PACKAGE OUTLINE





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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT	NOTE
INPUT				
Forward Current	I_F	60	mA	
Peak Forward Current	I_{FP}	1	A	1
Reverse Voltage	V_R	6	V	
Input Power Dissipation	P_I	100	mW	
OUTPUT				
Collector - Emitter Voltage	V_{CEO}	80	V	
Emitter - Collector Voltage	V_{ECO}	6	V	
Collector Current	I_C	50	mA	
Output Power Dissipation	P_O	150	mW	
COMMON				
Total Power Dissipation	P_{tot}	200	mW	
Isolation Voltage	V_{iso}	5000	Vrms	2
Operating Temperature	T_{opr}	-55~110	°C	
Storage Temperature	T_{stg}	-55~125	°C	
Soldering Temperature	T_{sol}	260	°C	

Note 1. 100 μ s pulse, 100Hz frequency

Note 2. AC For 1 Minute, R.H. = 40 ~ 60%



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ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C							
PARAMETER	SYMBOL	MIN	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	V _F	-	1.24	1.4	V	IF=10mA	
Reverse Current	I _R	-	-	10	μA	VR=6V	
Input Capacitance	C _{in}	-	10	-	pF	V=0, f=1kHz	
OUTPUT							
Collector Dark Current	I _{CEO}	-	-	100	nA	VCE=20V, IF=0	
Collector-Emitter Breakdown Voltage	BV _{CEO}	80	-	-	V	IC=0.1mA, IF=0	
Emitter-Collector Breakdown Voltage	BV _{ECO}	6	-	-	V	IE=0.1mA, IF=0	
TRANSFER CHARACTERISTICS							
Current Transfer Ratio	MPC816A1	CTR	80	-	160	IF=5mA, VCE=5V	
	MPC816B1		130	-	260		
	MPC816C1		200	-	400		
	MPC816D1		300	-	600		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	-	0.06	0.2	V	IF=20mA, IC=1mA	
Isolation Resistance	R _{ISO}	10 ¹²	10 ¹⁴	-	Ω	DC500V, 40 ~ 60% R.H.	
Floating Capacitance	C _{IO}	-	0.4	1	pF	V=0, f=1MHz	
Cut-off Frequency	f _c	-	80	-	kHz	VCE=2V, IC=2mA RL=100Ω, -3dB	3
Response Time (Rise)	t _r	-	6	18	μs	VCE=2V, IC=2mA RL=100Ω	4
Response Time (Fall)	t _f	-	8	18	μs		4

Note 3. Fig.12&13

Note 4. Fig.14

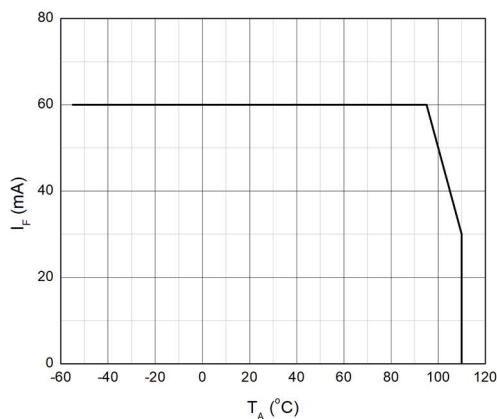


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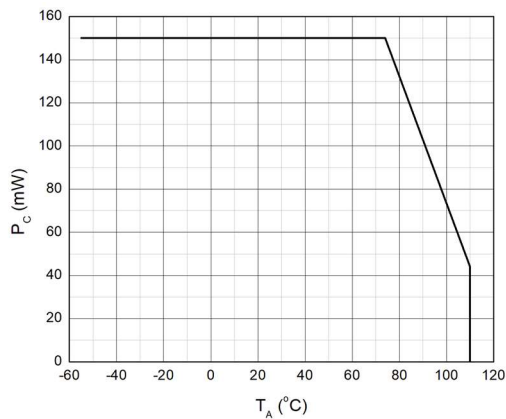
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CHARACTERISTIC CURVES

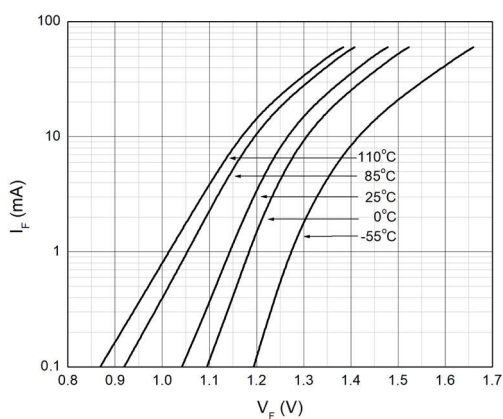
**Fig.1 Forward Current
vs. Ambient Temperature**



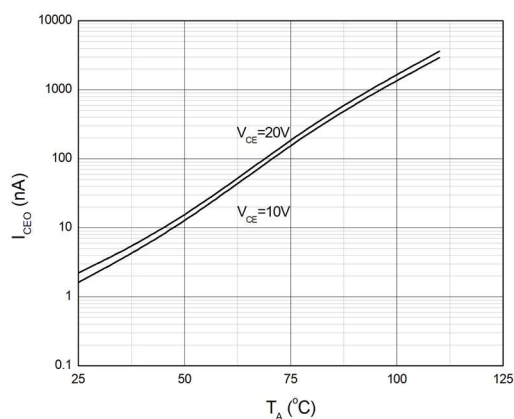
**Fig.2 Collector Power Dissipation
vs. Ambient Temperature**



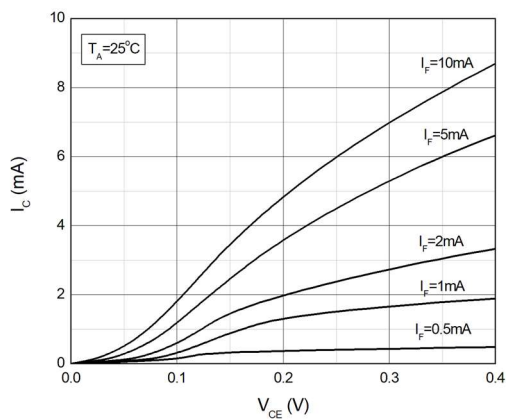
**Fig.3 Forward Current
vs. Forward Voltage**



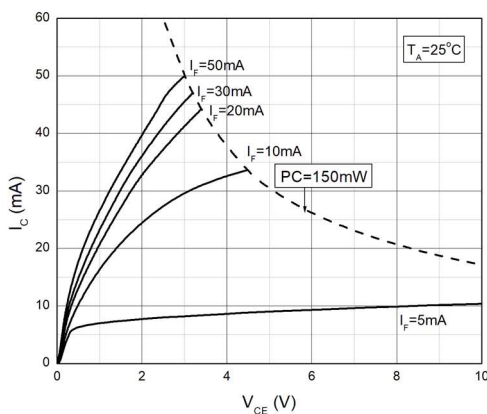
**Fig.4 Collector Dark Current
vs. Ambient Temperature**



**Fig.5 Collector Current
vs. Collector-emitter Voltage**



**Fig.6 Collector Current
vs. Collector-emitter Voltage**





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CHARACTERISTIC CURVES

Fig.7 Normalized Current Transfer Ratio vs. Forward Current

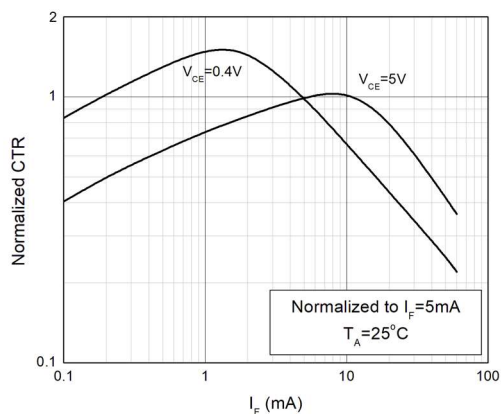


Fig.8 Normalized Current Transfer Ratio vs. Ambient Temperature

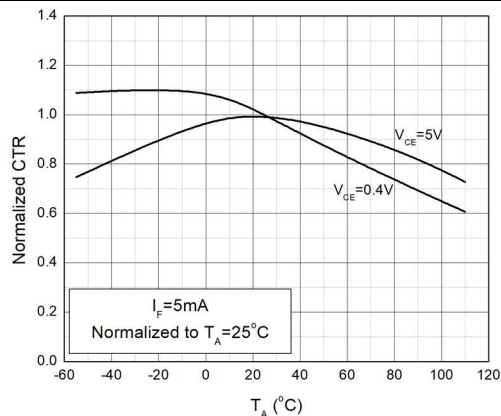


Fig.9 Collector-emitter Saturation Voltage vs. Ambient Temperature

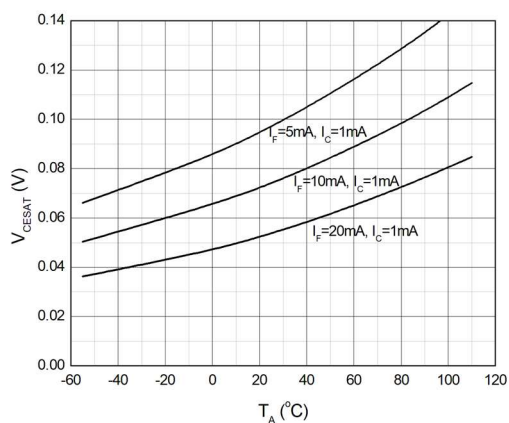


Fig.10 Switching Time vs. Load Resistance

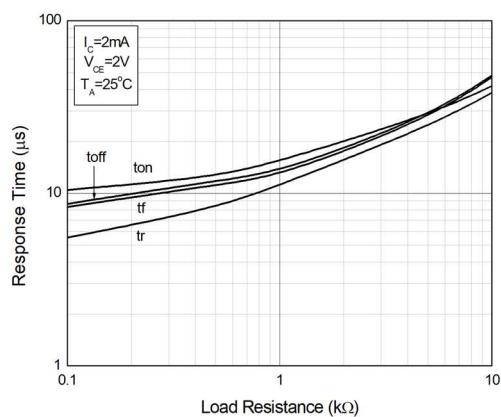
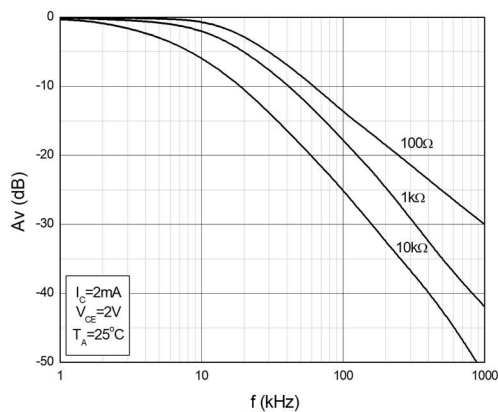


Fig.11 Frequency Response





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TEST CIRCUITS

Fig.12 Test Circuits of Response Time

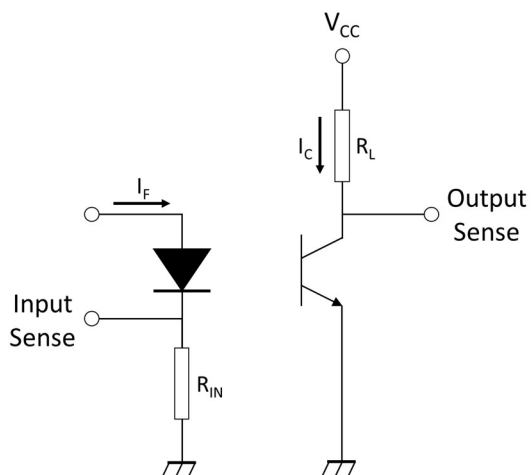


Fig.13 Curves of Response Time

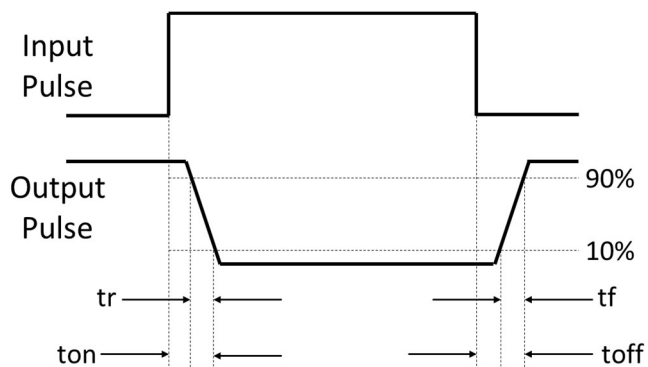
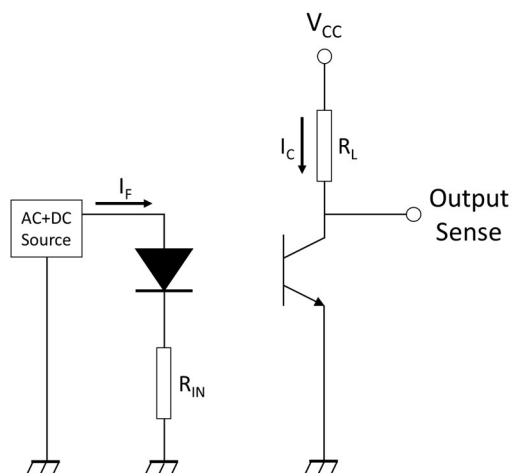


Fig.14 Test Circuits of Frequency Response



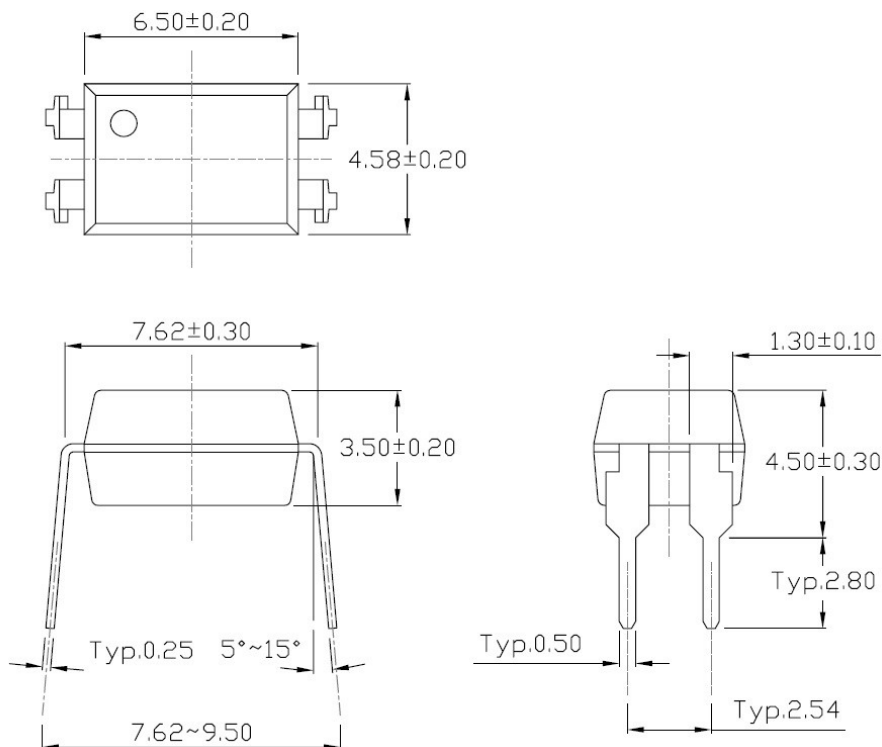


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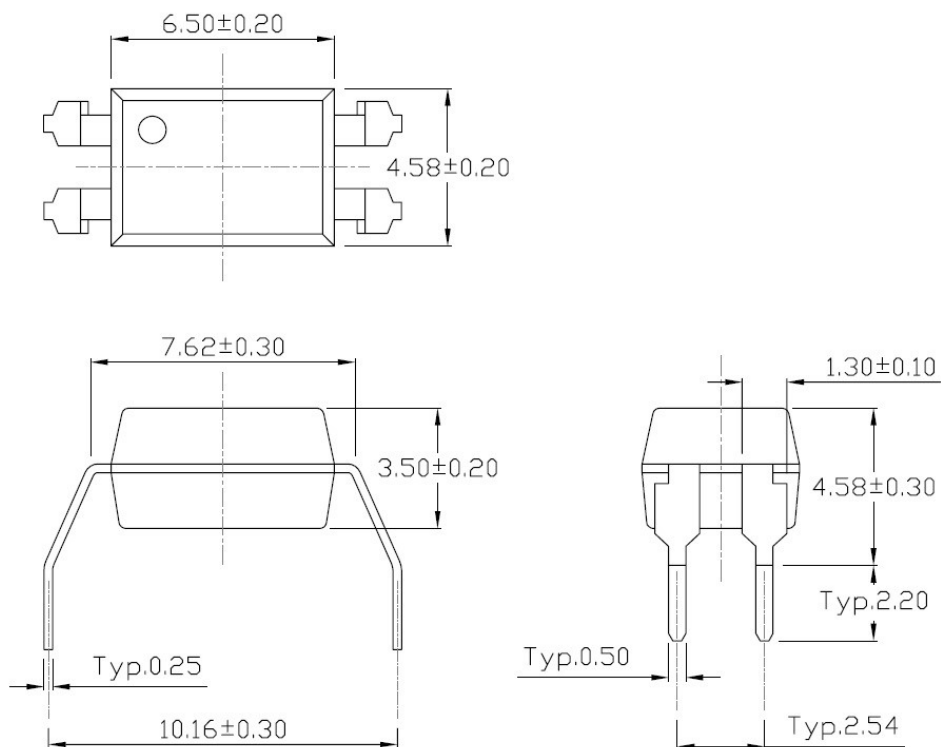
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PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Standard DIP – Through Hole (DIP Type)



Gullwing (400mil) Lead Forming – Through Hole (M Type)



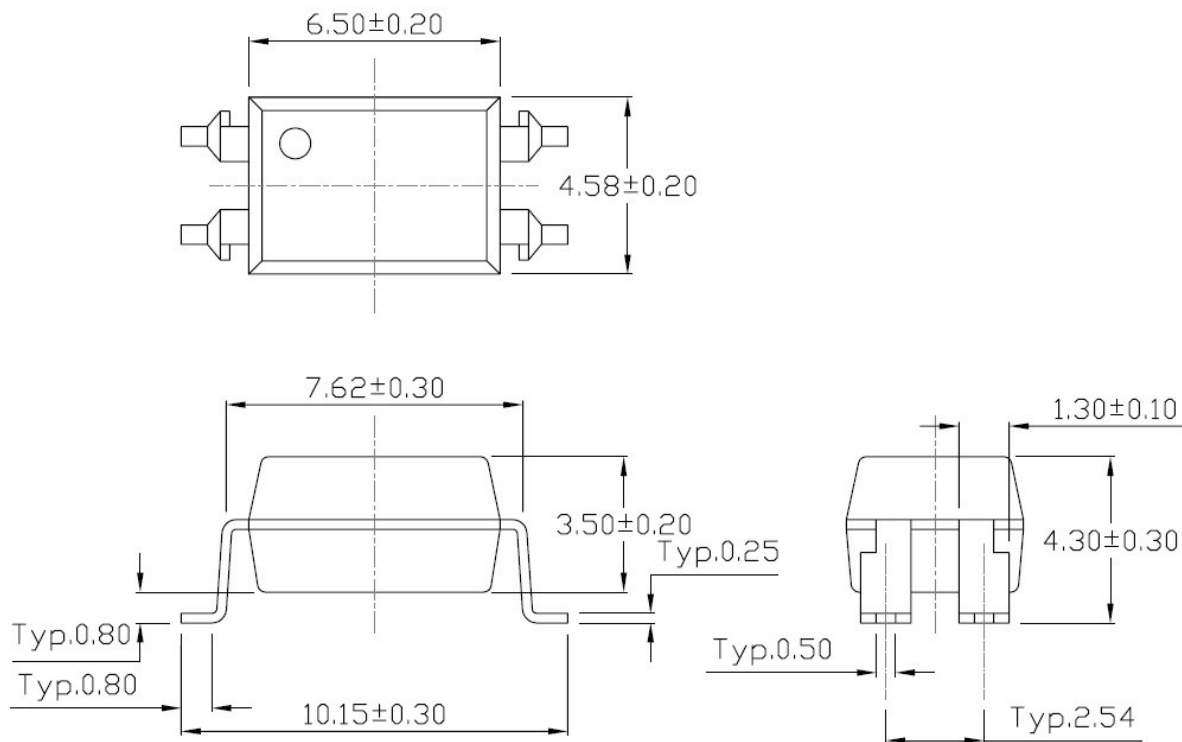


MPC816X1 Series

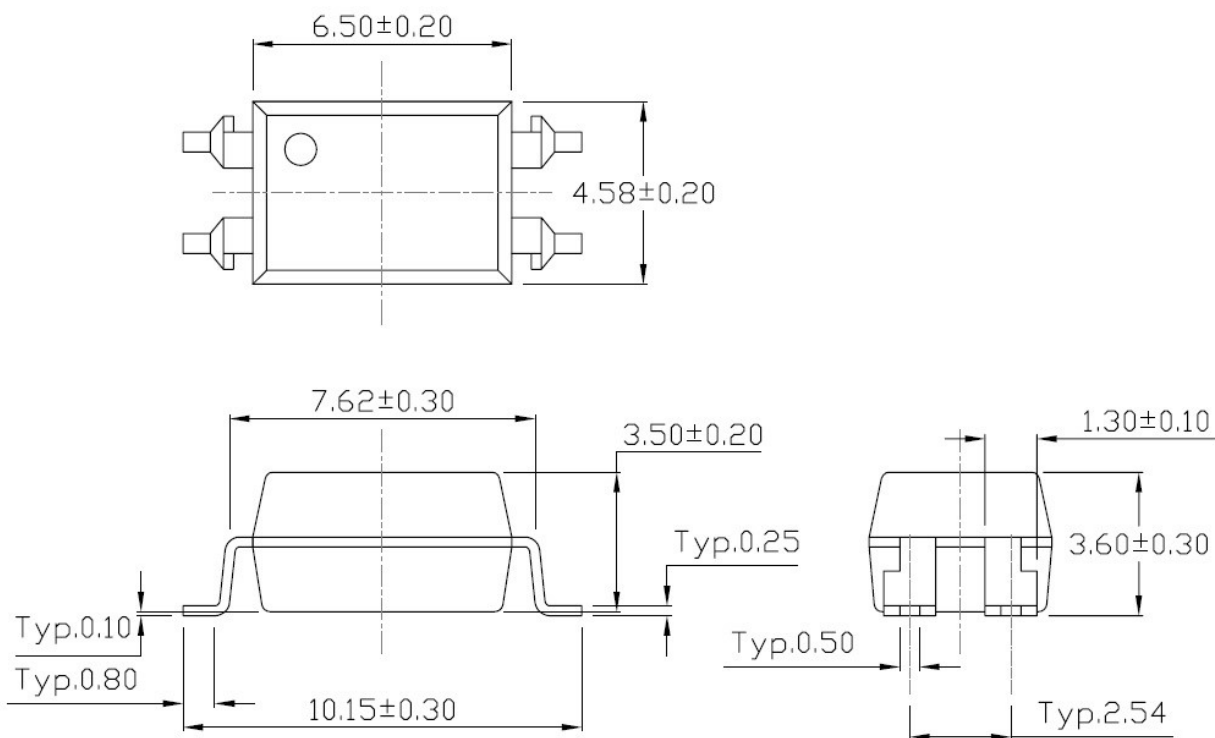
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PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Surface Mount Lead Forming (S Type)



Surface Mount (Low Profile) Lead Forming (SL Type)



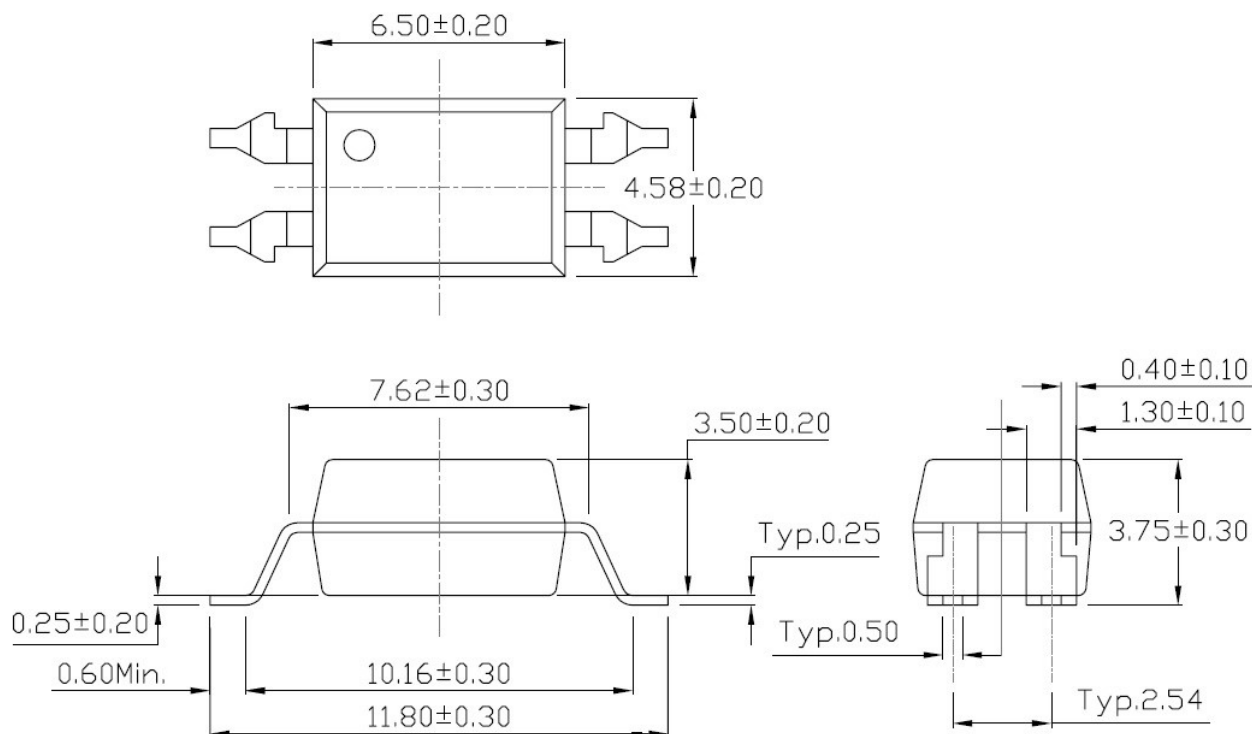


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DIP4, DC Input, Photo Transistor Coupler

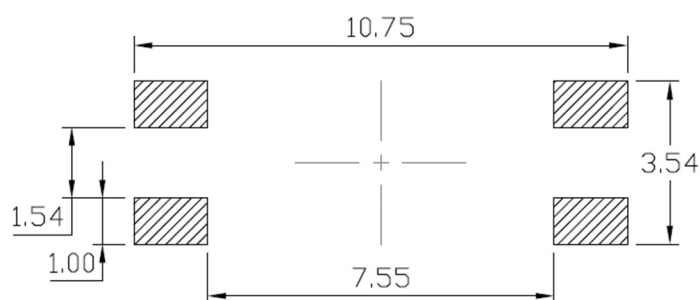
PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Surface Mount (Gullwing) Lead Forming (SLM Type)

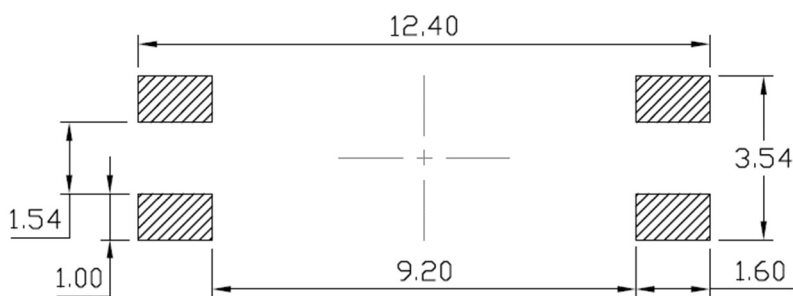


RECOMMENDED SOLDER MASK (Dimensions in mm unless otherwise stated)

Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



Surface Mount (Gullwing) Lead Forming



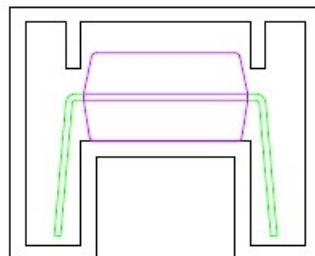
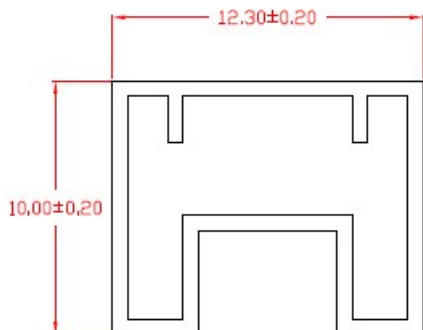


MPC816X1 Series

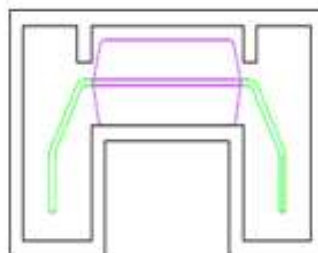
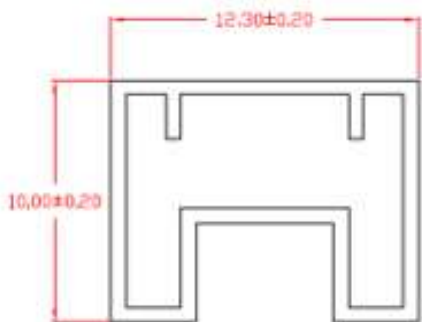
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TUBE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Standard DIP



Option M

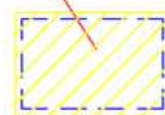




DIP4, DC Input, Photo Transistor Coupler

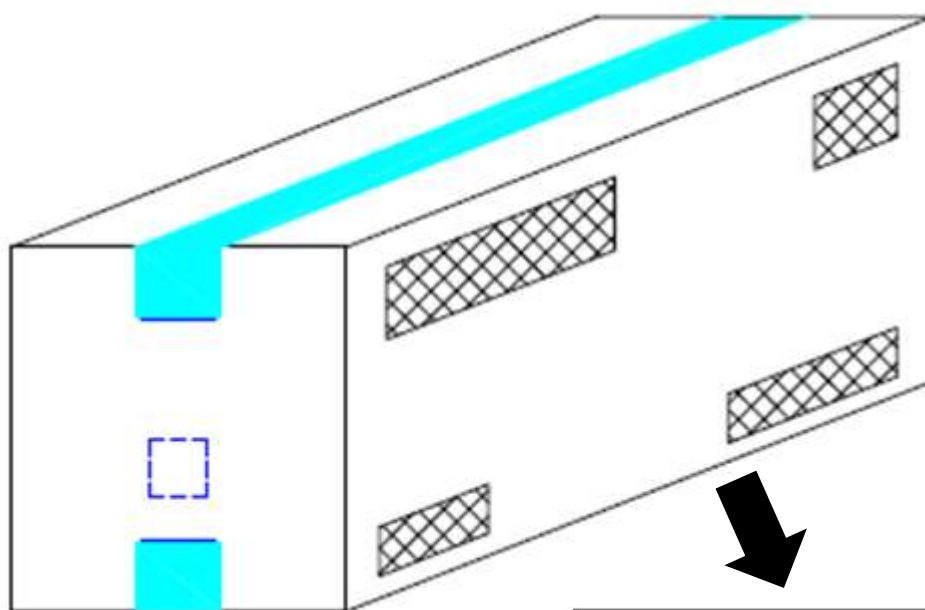
BOX SPECIFICATIONS (Tube Type)

Inner Box



- L x W x H = 52.5cm x 10.7cm x 4.7cm

Outer Box



- L x W x H = 53.5cm x 23.5cm x 25.5cm



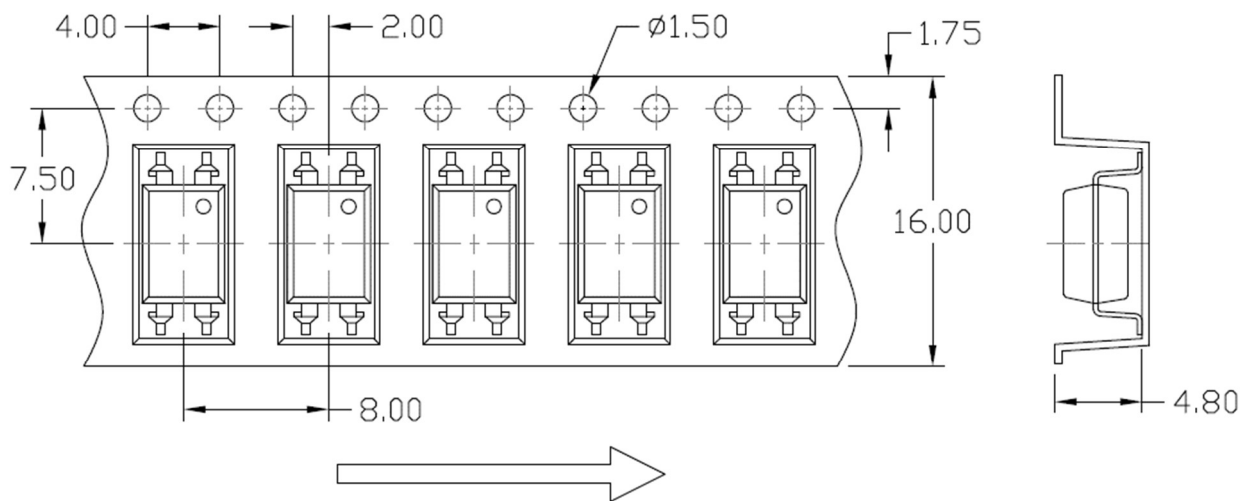


MPC816X1 Series

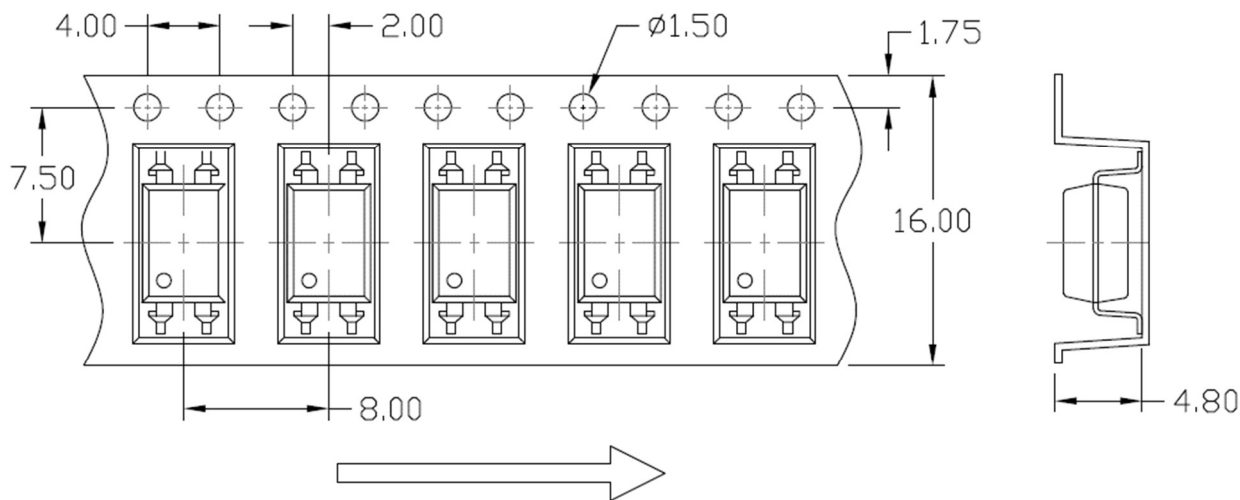
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CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S(T1) & SL(T1)



Option S(T2) & SL(T2)



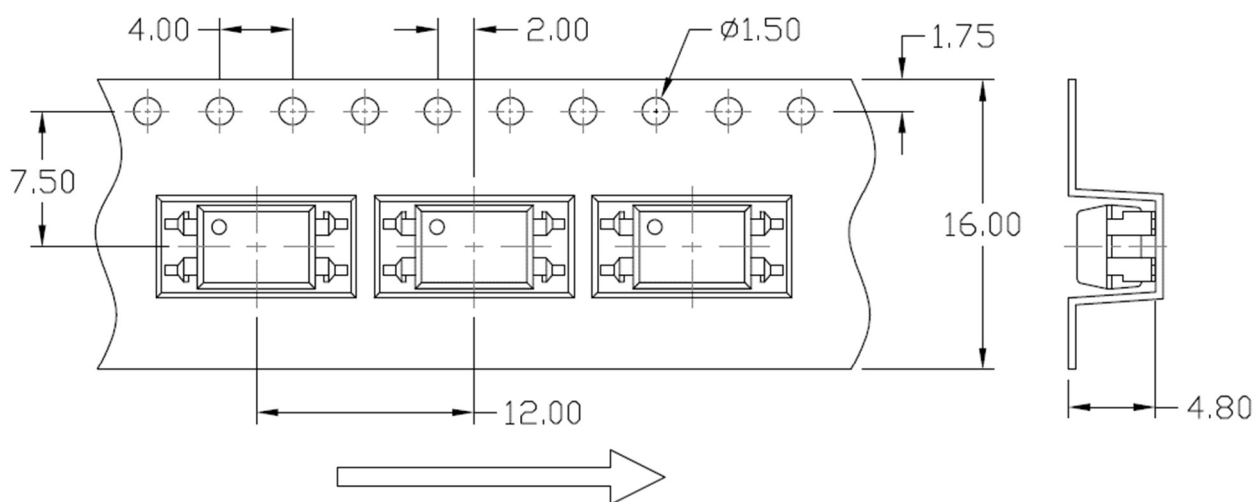


MPC816X1 Series

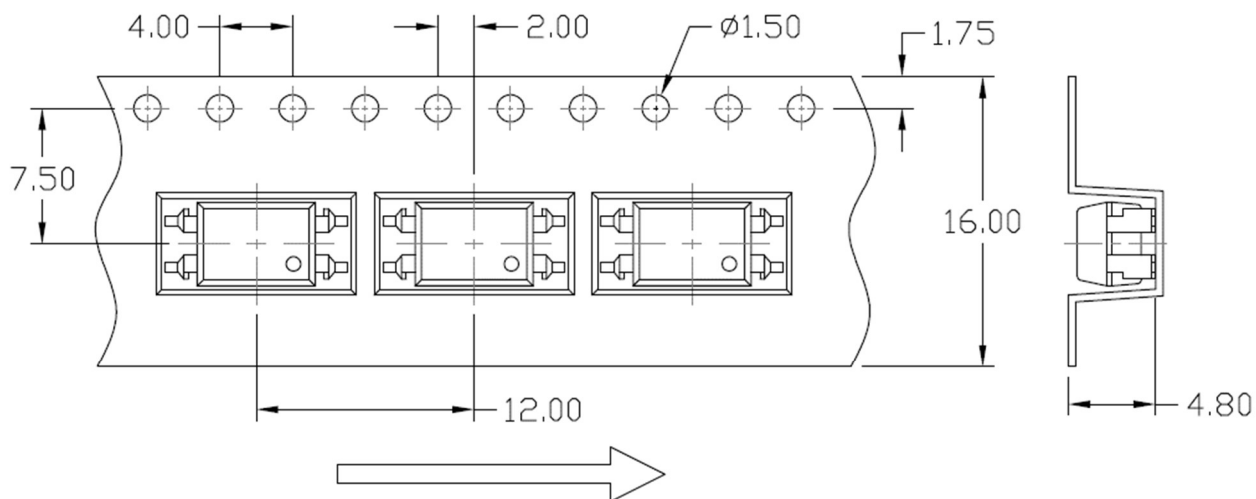
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CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S(T3) & SL(T3)



Option S(T4) & SL(T4)



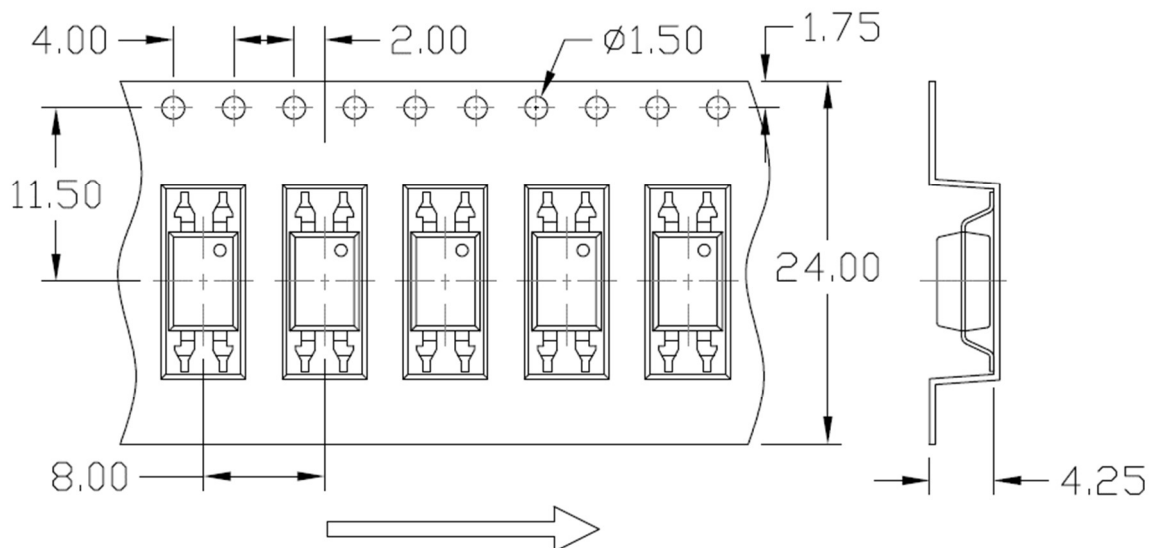


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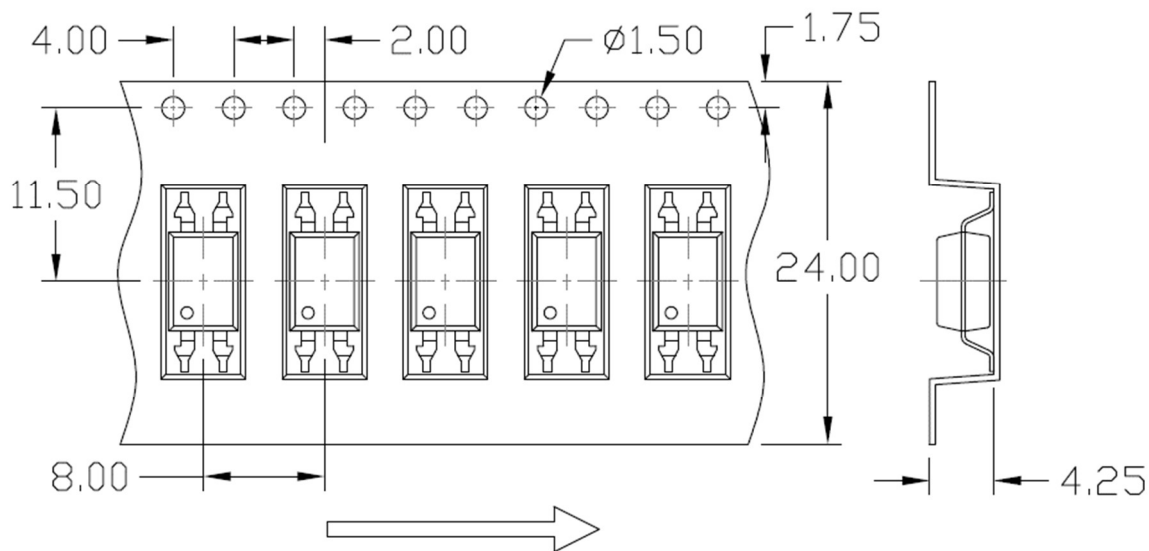
DIP4, DC Input, Photo Transistor Coupler

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option SLM(T1)



Option SLM(T2)



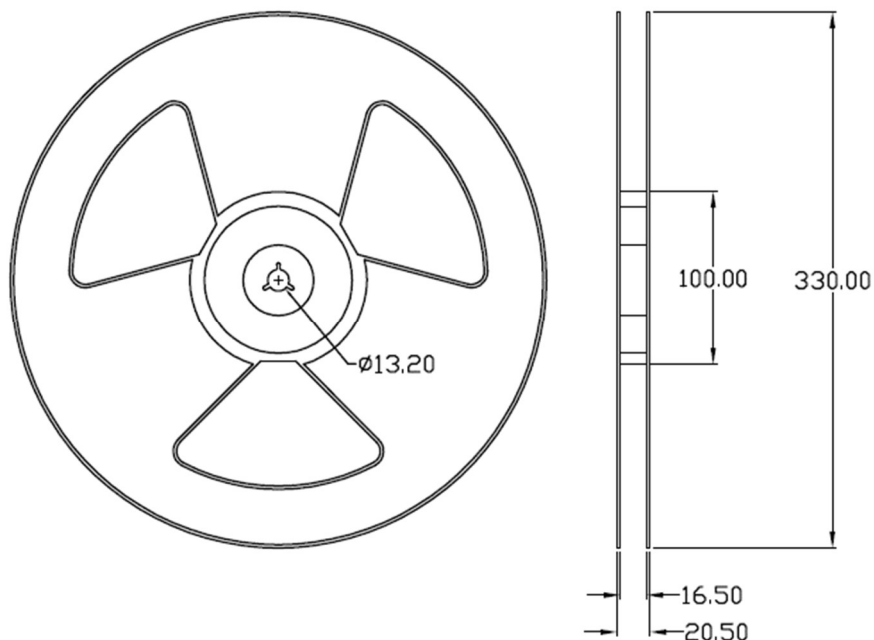


MPC816X1 Series

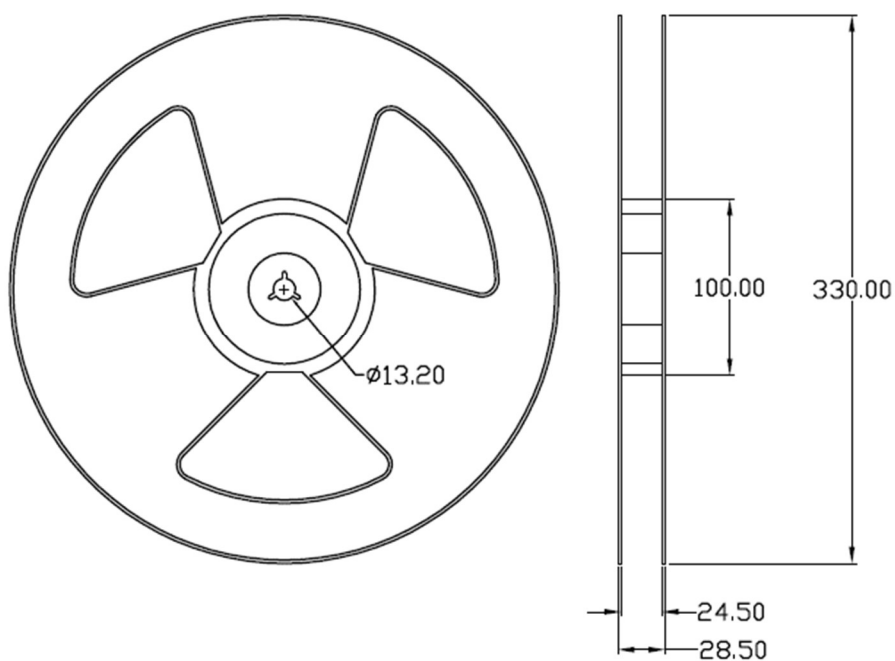
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REEL SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Option S & Option SL



Option SLM





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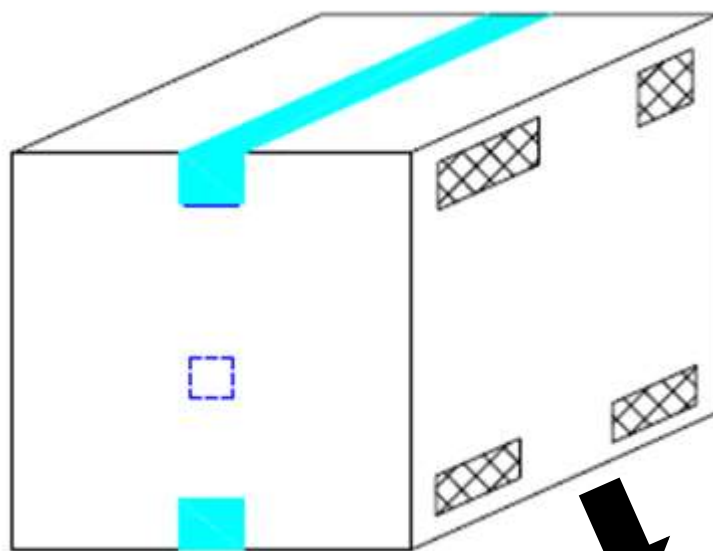
BOX SPECIFICATIONS (Reel Type)

Inner Box

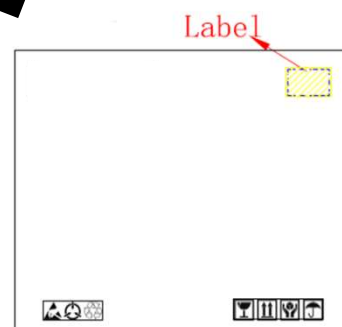


- L x W x H = 36cm x 36cm x 6.9cm

Outer Box



- L x W x H = 45cm x 38cm x 38cm



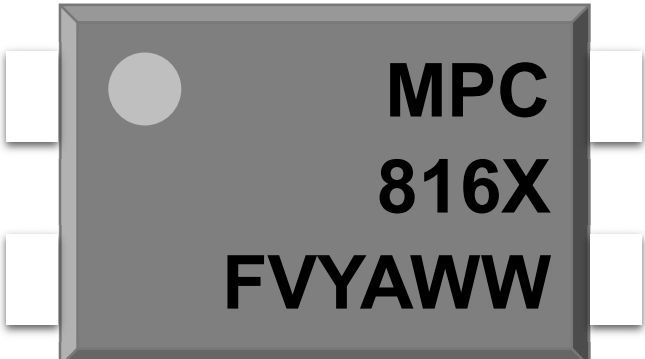


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ORDERING AND MARKING INFORMATION

MARKING INFORMATION

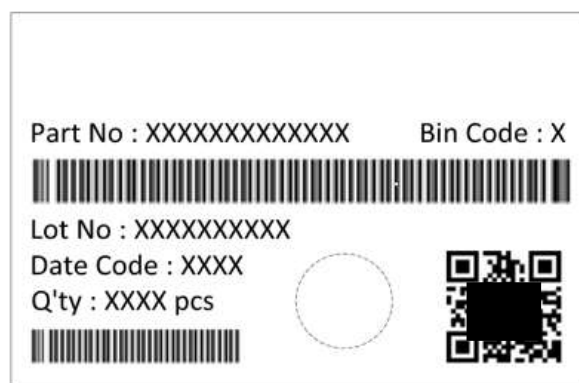
 <p>MPC 816X FVYAWW</p>	<p>MPC : Company Abbr. 816 : Part Number X : CTR Rank F : Leadframe Option V : VDE Option Y : Fiscal Year A : Manufacturing Code WW : Work Week</p>
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ORDERING INFORMATION

LABEL INFORMATION

MPC816X1(Y)(Z) -(F)(G)(V)

MPC – Company Abbr.
816 – Part Number
X1 – Rank (A1/B1/C1/D1)
Y – Lead Form Option (M/S/SL/SLM/None)
Z – Tape and Reel Option (T1/T2/T3/T4)
F – Leadframe Option (F:Iron, None:Copper)
G – Green Option (G or None)
V – VDE Option (V or None)



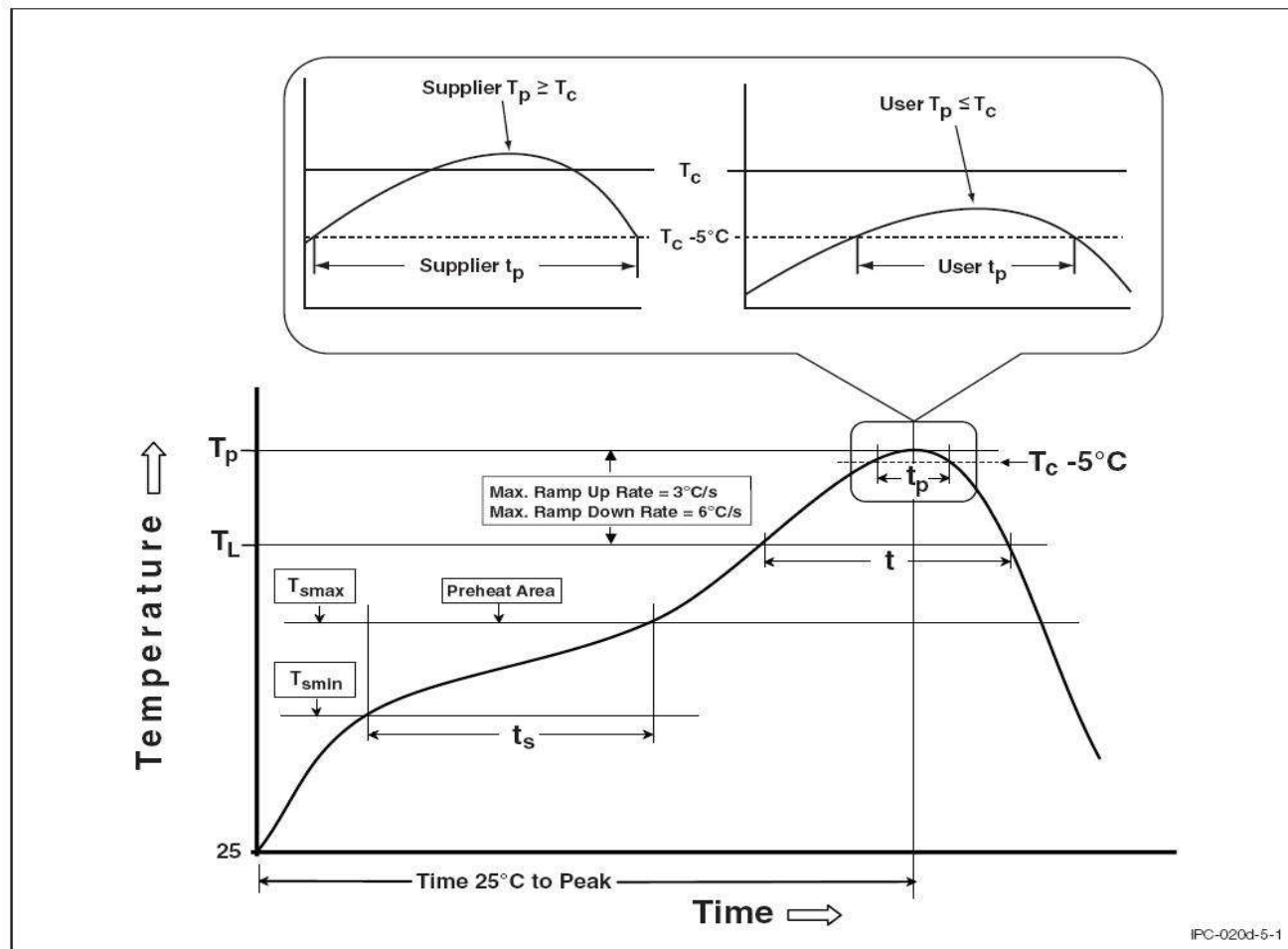
Packing Quantity

Option	Quantity	Quantity – Inner box	Quantity – Outer box
None	100 Units/Tube	32 Tubes/Inner box	10 Inner box/Outer box = 32k Units
M	100 Units/Tube	28 Tubes/Inner box	10 Inner box/Outer box = 32k Units
S(T1)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
S(T2)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
S(T3)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
S(T4)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SL(T1)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
SL(T2)	1500 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 22.5k Units
SL(T3)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SL(T4)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SLM(T1)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units
SLM(T2)	1000 Units/Reel	3 Reels/Inner box	5 Inner box/Outer box = 15k Units



REFLOW INFORMATION

REFLOW PROFILE



Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T_{smin})	100°C	150°C
Temperature Max. (T_{smax})	150°C	200°C
Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t_L to T_p)	3°C/second max.	3°C/second max.
Liquidous Temperature (T_L)	183°C	217°C
Time (t_L) Maintained Above (T_L)	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (t_p) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T_p to T_L)	6°C/second max	6°C/second max
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.



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DISCLAIMER

- WISELITE is continually improving the quality, reliability, function and design. WISELITE reserves the right to make changes without further notices.
- The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.
- WISELITE makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, WISELITE disclaims (a) any and all liability arising out of the application or use of any product, (b) any and all liability, including without limitation special, consequential or incidental damages, and (c) any and all implied warranties, including warranties of fitness for particular
- The products shown in this publication are designed for the general use in electronic applications such as office automation, equipment, communications devices, audio/visual equipment, electrical application and instrumentation purpose, non-infringement and merchantability.
- This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.
- Please contact WISELITE sales agent for special application request.
- Immerge unit's body in solder paste is not recommended.
- Parameters provided in datasheets may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated in each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify WISELITE's terms and conditions of purchase, including but not limited to the warranty expressed therein.



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版本 Rev.	生效日期 Effective Date	作者 Applicant	內容 Change Description
1.0	—	—	—
1.1	2021/2/25	Christina Lin	MARKING INFORMATION 正印標示修改:第二行第一個字母“F”移至第三行第一個字母
1.2	2021/4/7	Christina Lin	MPC-816X1 Series 去除字符“-”； ORDERING AND MARKING INFORMATION 中 MPC-816X1(Y)(Z)-FGV 修正為 MPC816X1(Y)(Z)-(F)(G)(V)、Green增加Non-Green之選項